

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Photointerrupter, Ultraminiature type

Absolute maximum ratings (Ta=25°C)

		• (•	
Parameter		Symbol	Limits	Unit
Input(LED)	Forward current	lF	50	mA
	Reverse voltage	VR	5	V
	Power dissipation	P□	80	mW
Output (photo- (transistor)	Collector-emitter voltage	VCEO	30	V
	Emitter-collector voltage	Veco	4.5	V
	Collector current	lc	30	mA
	Collector power dissipation	Pc	80	mW
Operating temperature		Topr	-25 to +85	°C
Storage temperature		Tstg	-40 to +100	°C

Applications

Optical control equipment Floppy disk drives

Features

Electrical and optical characteristics (Ta=25°C)

	Davamatar	Cumbal	Min.	T	Max.	Unit	Conditions	
Parameter		Symbol	IVIIII.	Тур.	wax.	Unit	Conditions	
Input charac- teristics	Forward voltage	VF	-	1.3	1.6	٧	I=50mA	
	Reverse current	lR	-	-	10	μΑ	V _R =5V	
Output charac- teristics	Dark current	ICEO	-	-	0.5	μΑ	Vce=10V	
	Peak sensitivity wavelength	λР	-	800	-	nm	_	
Transfer charac- teristics	Collector current	lc	0.18	-	1.08	mA	Vce=0.7V, Ir=3mA	
	Collector-emitter saturation voltage	V _{CE(sat)}	-	-	0.3	V	I _F =20mA, I _C =0.3mA	
	Response time	tr-tf	-	10	-	μs	Vcc=5V, I=20mA, RL=100Ω	
Infrared light emitter diode	Cut-off frequency	fc	-	1	-	MHz	Ir=50mA * Non-coherent Infrared light emitting diode used.	
	Peak light emitting wavelength	λР	-	950	-	nm		
Photo transistor	Response time	tr-tf	-	10	-	μs	$\begin{array}{c} V_{\text{CC}}\!=\!5V,\ l_{\text{C}}\!=\!1\text{mA},\ R_{\text{L}}\!=\!100\Omega\\ *\text{This product is not designed to be protected against electromagnetic wave}. \end{array}$	
	Maximum sensitivity wavelength	λρ	_	800	-	nm	-	

Electrical and optical characteristics curves

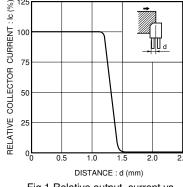


Fig.1 Relative output current vs. distance (I)

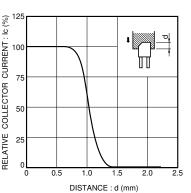


Fig.4 Relative output current vs. distance (II)

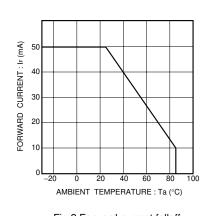


Fig.2 Forward current falloff

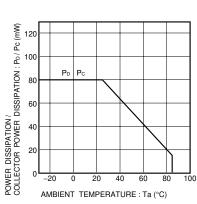


Fig.5 Power dissipation / collector power dissipation vs. ambient temperature

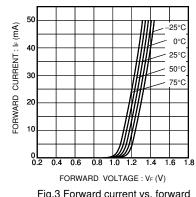


Fig.3 Forward current vs. forward

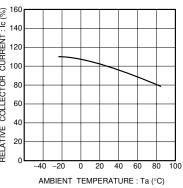
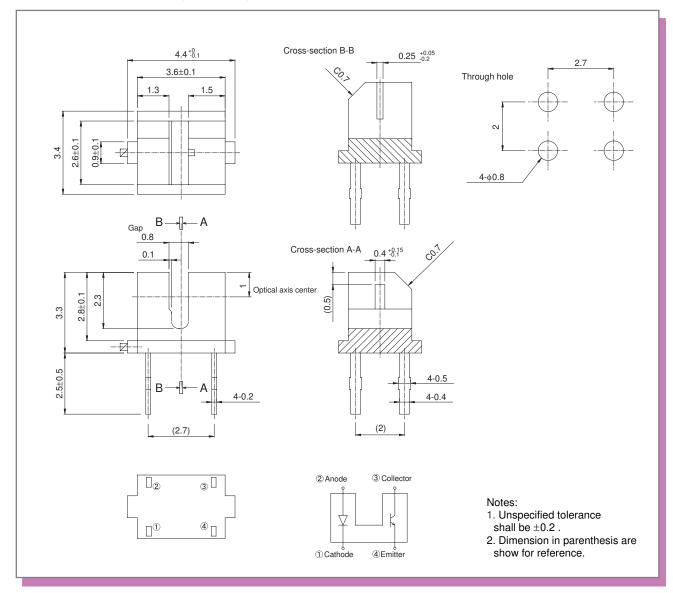


Fig.6 Relative output vs. ambient

External dimensions (Unit:mm)



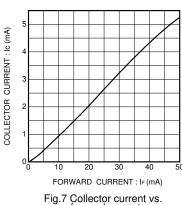


Fig.7 Collector current vs. forward current

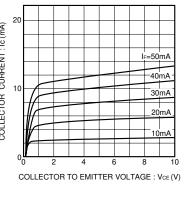


Fig.10 Output characteristics

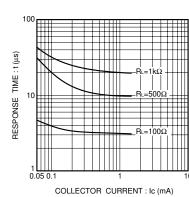
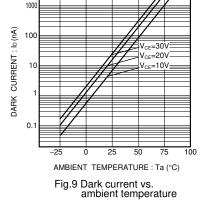


Fig.8 Response time vs. collector current



- $t_{\mbox{\tiny f}}$:Rise time (time for output current to rise from 10% to 90% of peak current)
- $t_{\rm f}$:Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.11 Response time measurement circuit

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any
 means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the
 product described in this document are for reference only. Upon actual use, therefore, please request
 that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
 otherwise dispose of the same, no express or implied right or license to practice or commercially
 exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.

